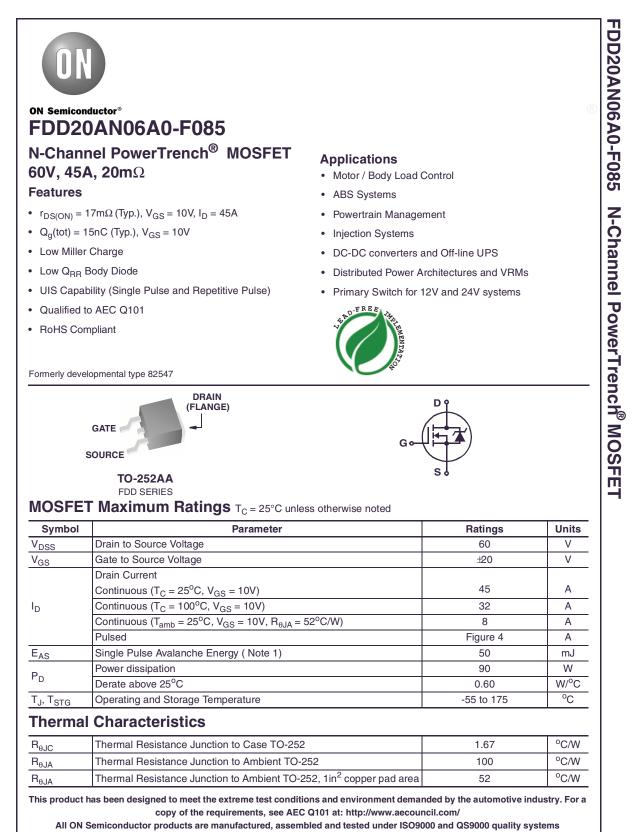
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# Onsemi

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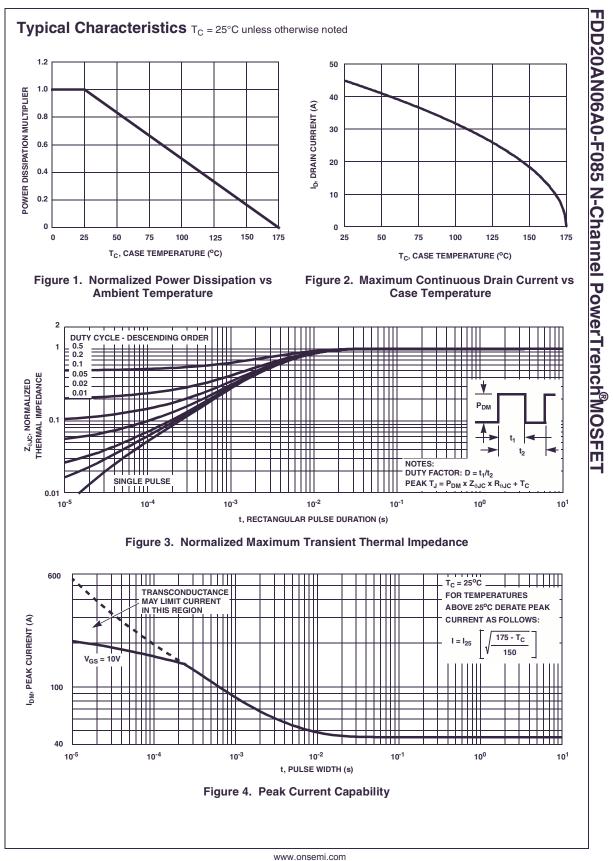


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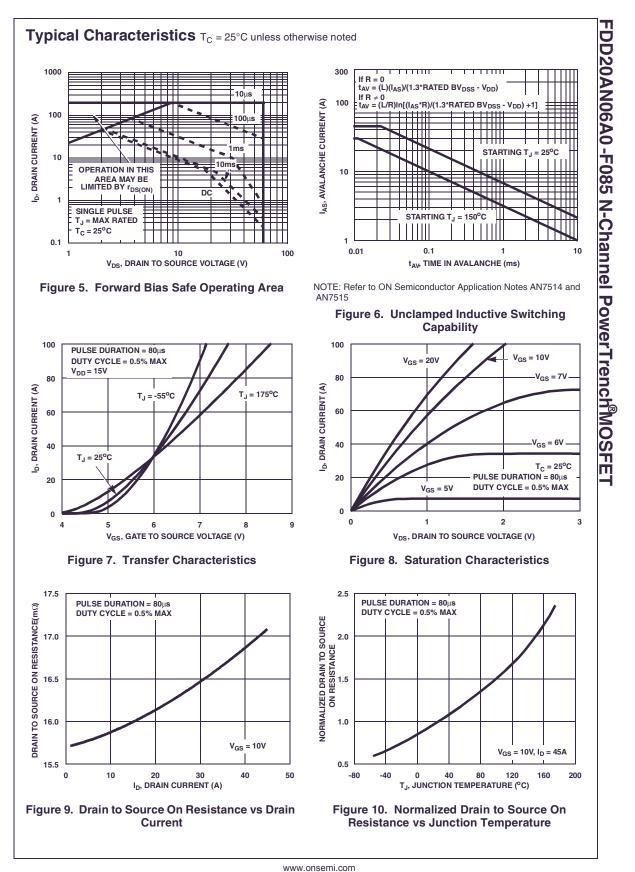
Publication Order Number: FDD20AN06A0-F085/D

Device Marking		Device	PackageReel SizeTO-252AA330mm		Tape Width 16mm		Quar	ntity	
FDD20AN06A0		FDD20AN06A0-F085					2500 units		
Electric	al Cha	racteristics T <sub>C</sub> = 25°C	C unless otherwi	se noted					
Symbol		Parameter	Test	Conditions	Min	Тур	Max	Units	
Off Chara	acteristic	s							
B <sub>VDSS</sub>		Drain to Source Breakdown Voltage		I <sub>D</sub> = 250μA, V <sub>GS</sub> = 0V		-	-	V	
				$V_{DS} = 50V$		-	1	v	
I <sub>DSS</sub>	Zero Gat	Zero Gate Voltage Drain Current		$T_{C} = 150^{\circ}C$	-	-	250	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current		$V_{GS} = 0V$ $T_{C} = 150^{\circ}C$ $V_{GS} = \pm 20V$		-	-	±100	nA	
					1	1	1		
	acteristic	-			2		1		
V <sub>GS(TH)</sub>	Gate to Source Threshold Voltage			$V_{GS} = V_{DS}, I_D = 250 \mu A$		-	4	V	
	Drain to Source On Resistance			$I_D = 45A, V_{GS} = 10V$ $I_D = 45A, V_{GS} = 10V,$ $T_{c} = 175^{\circ}C$		0.017	0.020	0	
r <sub>DS(ON)</sub>			I <sub>D</sub> = 45A, V <sub>0</sub> T <sub>J</sub> = 175°C			0.039	0.047	Ω	
	1		ij=175°C		1				
Dynamic	Charact	eristics							
C <sub>ISS</sub>	Input Cap	pacitance			-	950	-	pF	
C <sub>OSS</sub>	Output C	Output Capacitance		V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1MHz		185	-	pF	
C <sub>RSS</sub>	Reverse	Transfer Capacitance			-	60	-	pF	
Q <sub>g(TOT)</sub>	Total Gat	e Charge at 10V	V <sub>GS</sub> = 0V to	10V		15	19	nC	
Q <sub>g(TH)</sub>	Threshol	d Gate Charge	$V_{GS} = 0V to$	2V V <sub>DD</sub> = 30V	-	2	2.6	nC	
Q <sub>gs</sub>	Gate to S	Source Gate Charge		$I_D = 45A$	-	6	-	nC	
Q <sub>gs2</sub>	Gate Cha	arge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	4	-	nC	
Q <sub>gd</sub>	Gate to D	Gate to Drain "Miller" Charge				4.5	-	nC	
Switchin	o Charac	teristics (V <sub>GS</sub> = 10V)							
	Turn-On				-	-	164	ns	
t <sub>ON</sub>		Delay Time	_		_	11	-	ns	
t <sub>d(ON)</sub> t <sub>r</sub>	Rise Tim			V <sub>DD</sub> = 30V, I <sub>D</sub> = 45A		98	-	ns	
t <sub>d(OFF)</sub>	Turn-Off Delay Time Fall Time Turn-Off Time			$V_{GS} = 10V, R_{GS} = 20\Omega$		23	-	ns	
t <sub>f</sub>						33	-	ns	
t <sub>OFF</sub>						-	84	ns	
			I		1	1	1		
Drain-So	urce Dio	de Characteristics							
V <sub>SD</sub>	Source to Drain Diode Voltage		$I_{SD} = 45A$			-	1.25	V	
			I <sub>SD</sub> = 22A		-	-	1.0	V	
t <sub>rr</sub>		Recovery Time		dl <sub>SD</sub> /dt = 100A/µs	-	-	32	ns	
Q <sub>RR</sub>	Reverse	Recovered Charge	I <sub>SD</sub> = 45A, o	dl <sub>SD</sub> /dt = 100A/μs	-	-	25	nC	

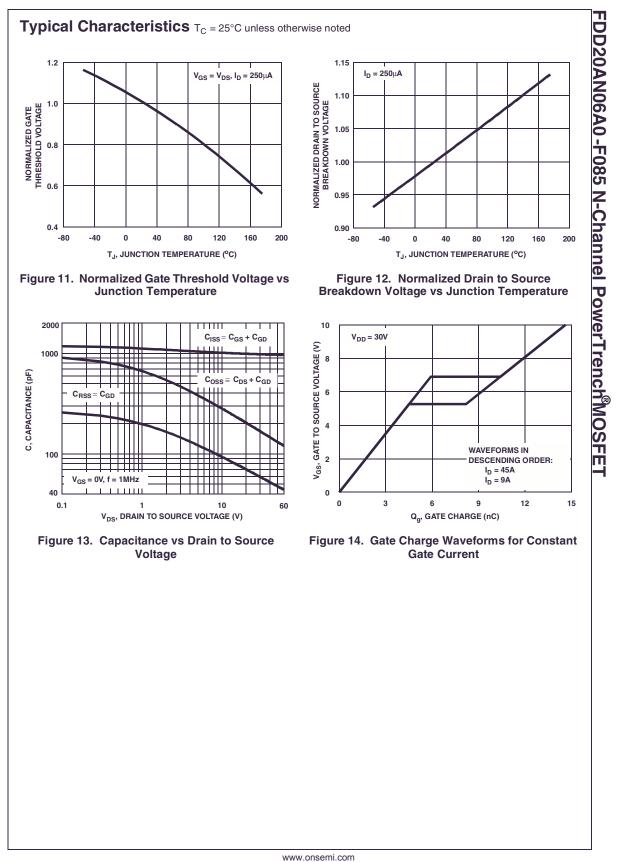
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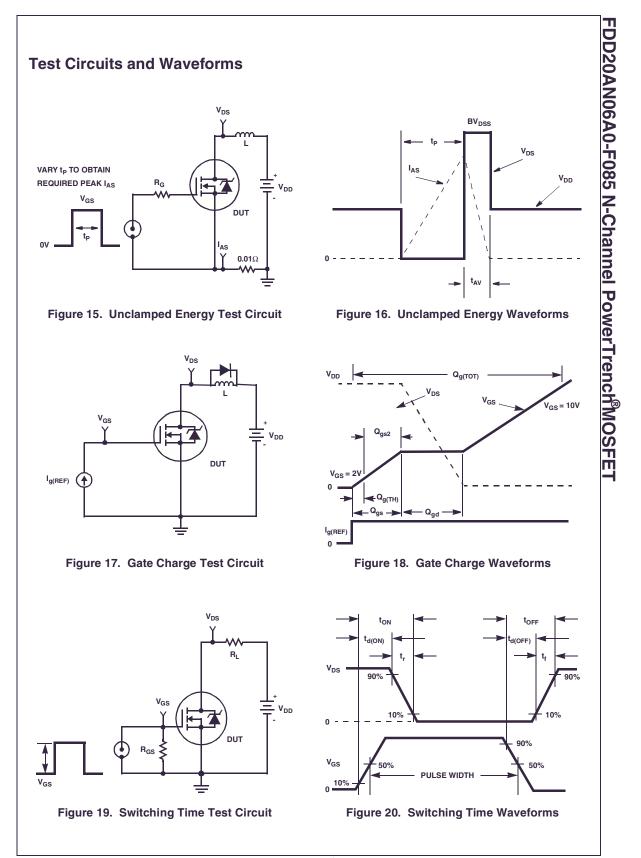






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## Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature,  $T_{JM}$ , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation,  $P_{DM}$ , in an application. Therefore the application's ambient temperature,  $T_A$  (°C), and thermal resistance  $R_{\theta JA}$  (°C/W) must be reviewed to ensure that  $T_{JM}$  is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of  $\mathsf{P}_{\mathsf{DM}}$  is complex and influenced by many factors:

- 1. Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

ON Semiconductor provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the  $R_{\theta JA}$  for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 10z copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the ON Semiconductor device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

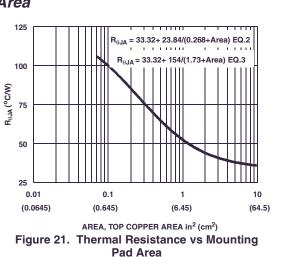
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

$$R_{\theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)}$$
 (EQ. 2)

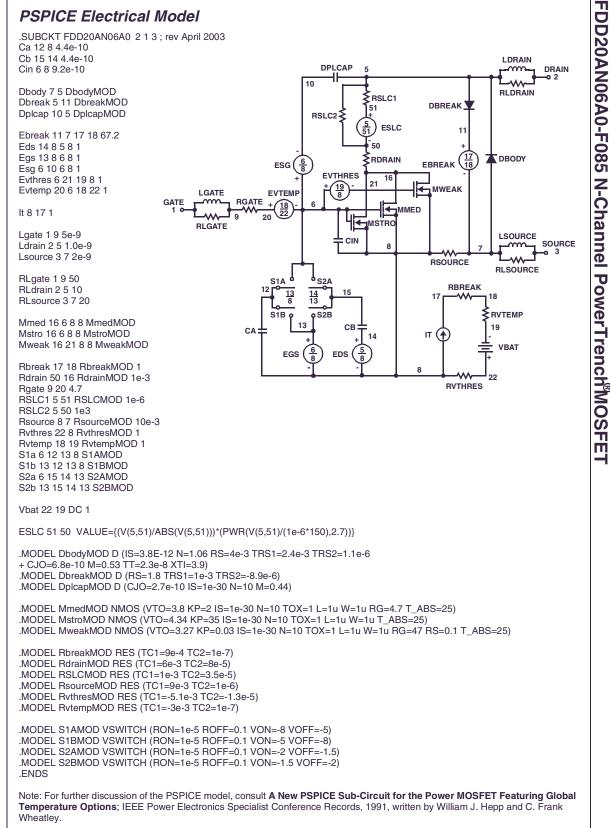
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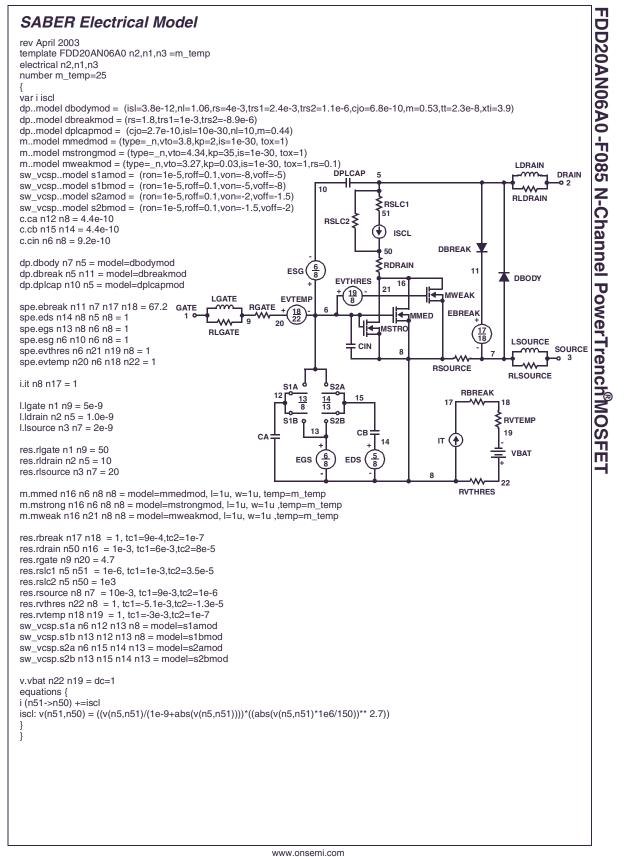
$$R_{\Theta JA} = 33.32 + \frac{154}{(1.73 + Area)}$$
 (EQ. 3)

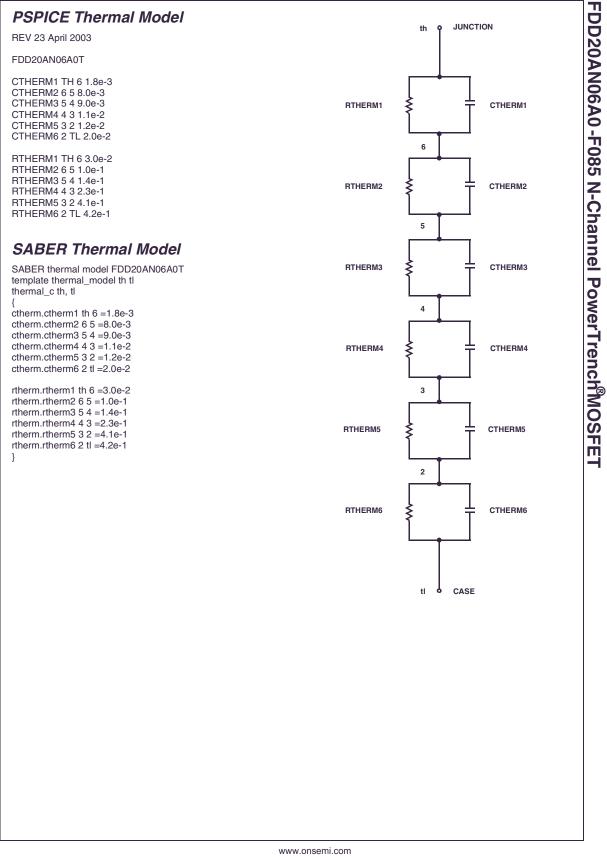
Area in Centimeters Squared



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